

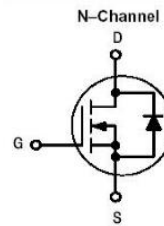
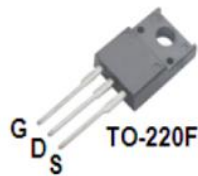


## GENERAL DESCRIPTION

The RZC8012TF is the high cell density trench N-Channel MOSFETs, which provide excellent RDS(ON) and gate charge for most of the synchronous buck converter applications.

The RZC8012TF meet the ROHS and Green Product requirement 100% EAS guaranteed with full function reliability approved.

## PIN CONFIGURATION



## FEATURES

- 80V/100A,  $R_{DS(ON)} = 12m\Omega$   $V_{GS} = 10V$  (MAX.)
- 80V/100A,  $R_{DS(ON)} = 15m\Omega$   $V_{GS} = 4.5V$  (MAX.)
- 100% EAS Guaranteed
- Green Device Available
- Supper Low Gate Charge
- Excellent Cdv/dt effect decline
- Advanced high cell density Trench technology
- TO-220F package design

## APPLICTIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch

## ORDERING INFORMATION

Part Number	Package	Top Marking
RZC8012TF	TO-220F	TF8012

**MAXIMUM RATINGS** ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Units	
Drain to Source Voltage	$V_{DSS}$	80	V	
Gate to Source Voltage	$V_{GSS}$	$\pm 20$	V	
Continuous Drain Current	$25^\circ\text{C}$	$I_D$	100	A
	$70^\circ\text{C}$		70	A
Pulsed Drain Current	$I_{D(pulse)}$	200	A	
Maximum Power Dissipation	$25^\circ\text{C}$	$P_D$	89	W
Single Pulse Avalanche Energy	EAS	80	mJ	
Operating Junction Temperature	$T_J$	150	$^\circ\text{C}$	
Storage Temperature	$T_{STG}$	-55-+150	$^\circ\text{C}$	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)	$T_L$	260	$^\circ\text{C}$	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

**ELECTRICAL CHARACTERISTICS** (TA = 25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX	Units
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>DS</sub> =250uA	80			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =64V, V <sub>GS</sub> =0V T <sub>J</sub> =25°C			1	uA
		V <sub>DS</sub> =64V, V <sub>GS</sub> =0V T <sub>J</sub> =55°C			5	uA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA
Gate threshold voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.2		2.5	V
Drain to Source On-state Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A		10	12	mΩ
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> =10A		12	15	mΩ
Gate Resistance	R <sub>g</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =0V, f=1MHz		0.66		Ω
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V, f=1MHz		3120		pF
Output Capacitance	C <sub>OSS</sub>			140		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			110		pF
Total Gate Charge (10V)	Q <sub>G</sub>	V <sub>DD</sub> =64V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		61		nC
Gate-Source Charge	Q <sub>GS</sub>			8.5		nC
Gate-Drain Charge	Q <sub>GD</sub>			18		nC
Turn-On Delay Time	T <sub>d(on)</sub>	V <sub>DD</sub> =40V, V <sub>GS</sub> =10V, R <sub>G</sub> =3.3Ω, I <sub>D</sub> =10A		12		nS
Rise Time	T <sub>r</sub>			25		
Turn-Off Delay Time	T <sub>d(off)</sub>			51		
Fall Time	T <sub>f</sub>			18		

Note : 1. Pulse test: pulse width ≤ 300us, duty cycle ≤ 2%.

2. Static parameters are based on package level with recommended wire-bonding.



### TYPICAL CHARACTERISTICS

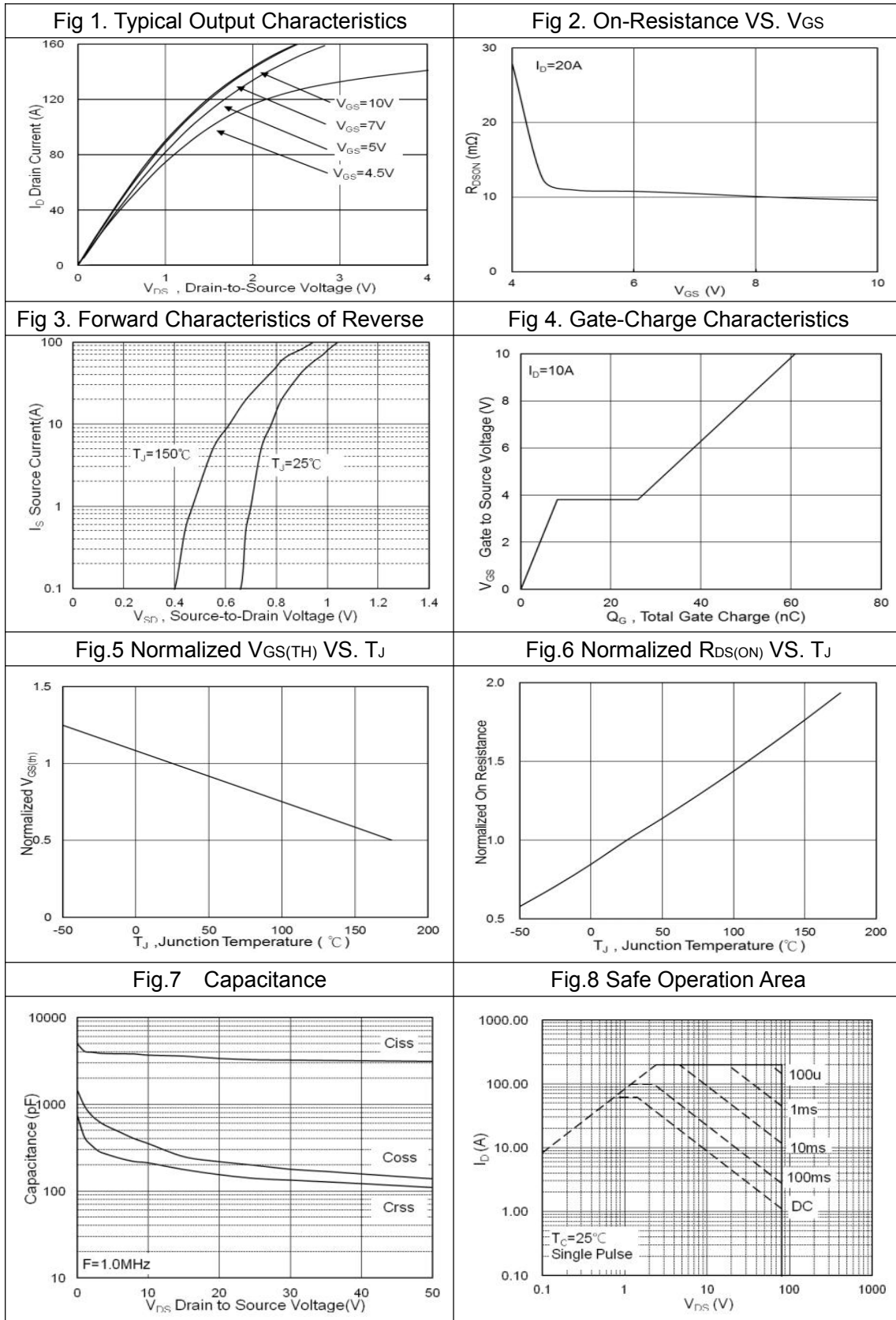
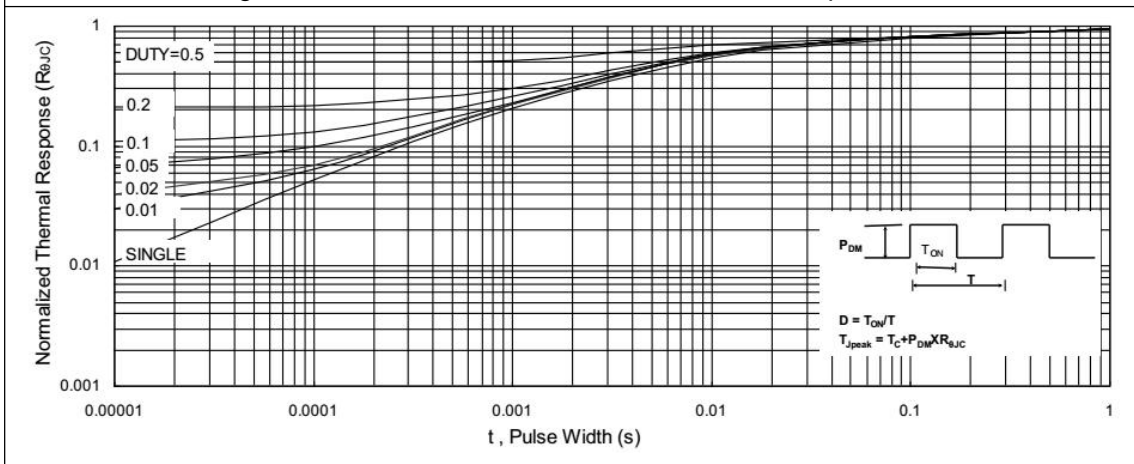
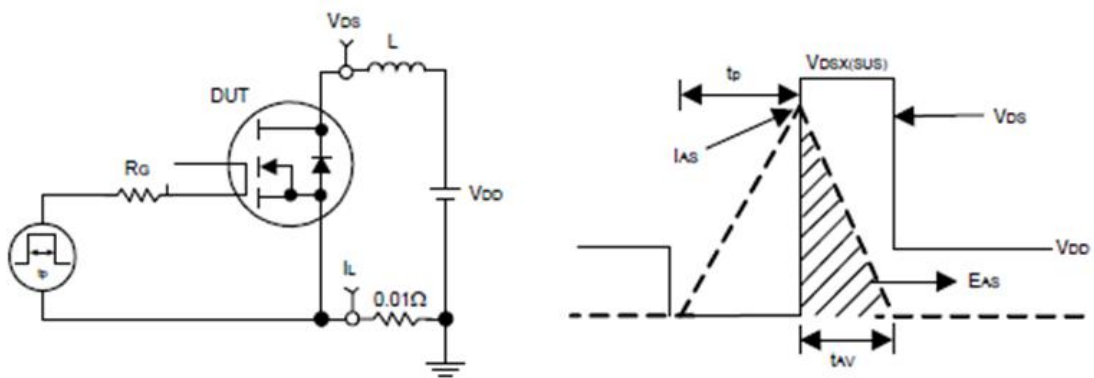




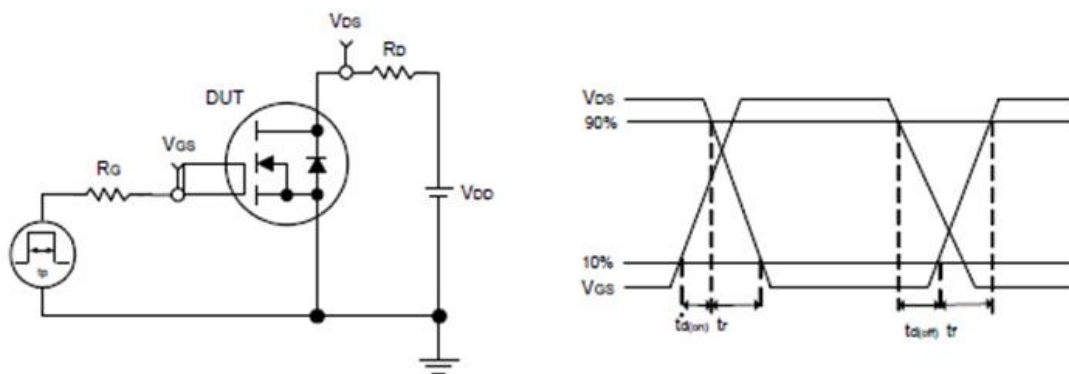
Fig.9 Normalized Maximum Transient Thermal Impedance



Avalanche Test Circuit and Waveforms



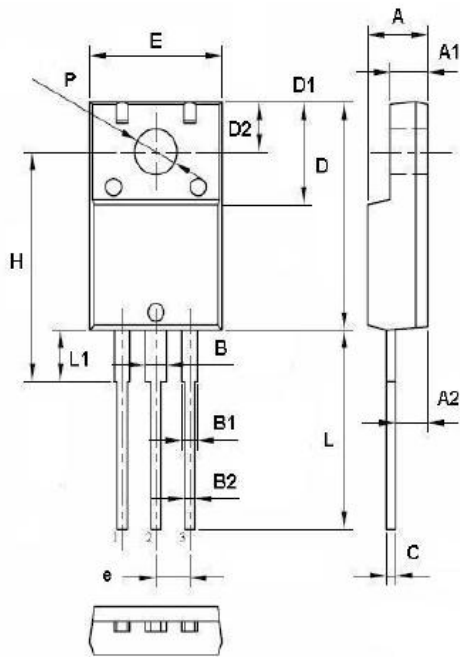
Switching Time Test Circuit and Waveforms





PACKAGE DIMENSIONS

TO-220F



TO-220F DIMENSION				
Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.200	4.800	0.165	0.189
A1	2.500	3.100	0.098	0.122
A2	2.100	2.700	0.083	0.106
B	1.300	1.900	0.051	0.075
B1	0.900	1.500	0.035	0.059
B2	0.650	1.050	0.026	0.041
C	0.400	1.000	0.016	0.039
D	15.700	16.300	0.618	0.642
D1	6.900	7.500	0.272	0.295
D2	3.200	3.800	0.126	0.150
E	9.700	10.300	0.382	0.406
e	2.350	2.750	0.093	0.108
H	15.800	16.400	0.622	0.646
L	13.500	14.500	0.531	0.571
L1	3.400	3.800	0.134	0.150